## NSN 5961-01-149-4070

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-149-4070 **Inclosure Material:** Glass **Overall Length:** 0.172 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.078 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-35 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 51.0 regulator voltage **Current Rating Per Characteristic:** 2.00 amperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0